imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

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RoHS Compliant

Actual Size 🗀

32.768kHz Series OX / OY Type 3.2 x 2.5 / 2.5 x 2.0 mm SMD Oscillator

FEATURE

- Tight symmetry (45 to 55%) available.
- Operation voltage: 1.8V, 2.5V, 3.3V
- Tri-state enable/disable
- Built-in ASIC enables reduction of current consumption.

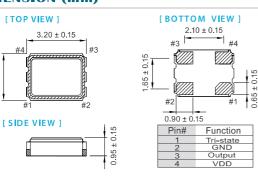
TYPICAL APPLICATION

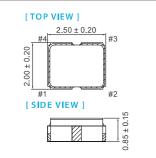
- Typically used for real time clock application.
- Mobile Phone

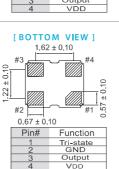
 2.50 ± 0.15

- DSC,Set-top Box ,HDTV
- Car navigation systems.

DIMENSION (mm)

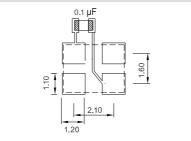




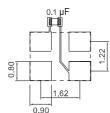


SOLDER PAD LAYOUT (mm)

Actual Size



To ensure optimal oscillator performance, place a by-pass capacitor of $0.1 \mu F$ as close to the part as possible between Vdd and GND pads.



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ELECTRICAL SPECIFICATION

Parameter	3.3V		2.5V		1.8V		Unit
	Min.	Max.	Min.	Max.	Min.	Max.	Offic
Supply Voltage Variation (VDD)	VDD-10%	VDD+10%	Vdd-10%	VDD+10%	Vdd-10%	VDD+10%	V
Supply Current (@ 15pF load)		70		66		63	uA
(@ no load)		65		62		60	uA
Duty Cycle	45	55	45	55	45	55	%
Output Level (CMOS) Output High (Logic "1")	2.97		2.25		1.62		V
Output Low (Logic "0")		0.33		0.25		0.18	
Transition Time:Rise/Fall Time+		50		50		50	nSec
Start Time		2		2		2	mSec
Tri-State(Input to Pin 1) Enable (High voltage or floating)	2.31		1.75		1.26		V
Disable (Low voltage or GND)		0.99		0.75		0.54	
Aging (@25°C 1 st year)		±3		±3		±3	ppm
Storage Temp. Range	-55	125	-55	125	-55	125	°C

Standard frequencies are frequencies which the crystal has been designed and does not imply a stock position

+Transition times are measured between 10% and 90% of VDD,withan output load of 15pF

FREQ.STABILITY vs. TEMP.RANGE

ppm Temp. (°C)	±20	±25	±40	±50
-10~+60	0	0	0	0
-20~+70	\triangle	0	0	0
-40~+85	×	\bigtriangleup	0	0
-40~+105	×	×	0	0
-40~+125	×	X	\triangle	0

* O: Available \triangle :Conditional X: Not available

*Inclusive of calibration @ 25°C, operating temperature range, input voltage variation, load variation, aging (1st year), shock, and vibration load variation

Note: not all combination of options are available. Other specifications may be available upon request.